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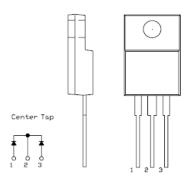
# MBRF3035CT /MBRF3040CT /MBRF3045CT SCHOTTKY RECTIFIER

#### **Applications:**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

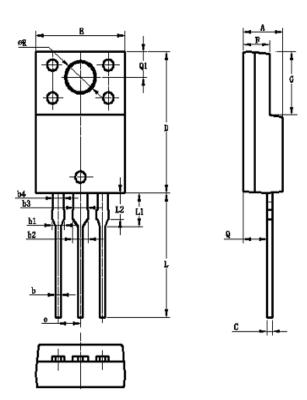
#### Features:

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



**OUTLINE DRAWING** 

#### **Mechanical Dimensions: In mm**

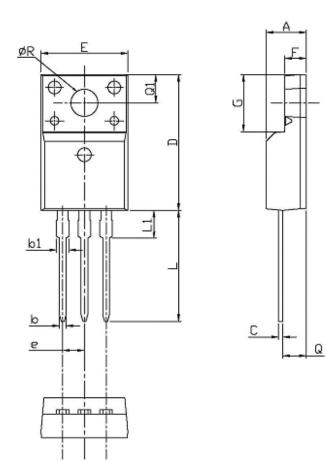


	OPTION 1(CJ)		OPTION 2(HD)	
Dim	Min	Max	Min	Max
Α	4.4	4.6	4.30	4.70
b	0.6T	ΥP	0.50	0.75
b1	1.3T	ΥP	1.30	1.40
b2	1.7T	ΥP	1.70	1.80
b3	1.6T	ΥP	1.50	1.75
b4	1.2T	ΥP	1.10	1.35
С	0.60TYP		0.50	0.75
D	14.8	15.1	14.80	15.20
Е	10.06	10.26	9.96	10.36
е	2.55TYP		2.54TYP	
F	2.9	3.1	2.80	3.20
G	6.5	6.9	6.50	6.90
L	12.7	13.7	12.8	13.2
L1	3.4	3.8	3.60	4.00
L2	2.6	3.0	-	-
Q	2.5	2.9	2.50	2.90
Q1	2.5	2.9	2.70	REF
ØR	3.5REF		3.50REF	

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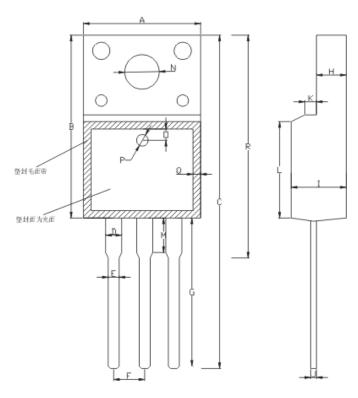
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	OPTION 3		ОРТІ	ON 4
Dim	Min	Max	Min	Max
Α	4.53	4.93	4.50	4.90
b	0.71	0.91	0.70	0.90
b1	1.15	1.39	1.33	1.47
С	0.36	0.53	0.45	0.60
D	15.67	16.07	15.67	16.07
E	9.96	10.36	9.96	10.36
е	2.54	ГҮР	2.54 BSC	
F	2.34	2.76	2.34	2.74
G	6.50	6.90	6.48	6.88
L	12.37	12.77	12.78	13.18
L1	2.23	2.63	3.03	3.43
Q	2.56	2.96	2.56	2.96
Q1	3.10	3.50	3.10	3.50
ØR	2.98	3.38	3.08	3.28



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A:10.20	$\pm 0.50$	B:15.90	$\pm0.50$	C:29.00	$\pm1.00$	D:1.24	$\pm 0.10$
E:0.80	$\pm 0.10$	F:2.54	$\pm 0.10$	G:13.10	$\pm 1,0$	H:2.55	$\pm 0.05$
I:4.70	$\pm 0.05$	J:0.50	$\pm 0.05$	K:1.20	$\pm 0.20$	L:8.00	$\pm 0.50$
M:3.00	$\pm 0.50$	N:3.20	$\pm 0.20$	O:1,25	$\pm 0.05$	P:1.5	$\pm 0.05$
Q:1.0	±0.20	R:19.2	±1.0				

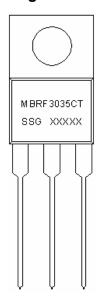
### **OPTION 5 (SR)**

#### **ITO-220AB**



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#### **Marking Diagram:**



Where XXXXX is YYWWL

MBR = Device Type F = Package type

30 = Forward Current (30A) 35 = Reverse Voltage (35V)

CT = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

#### **Ordering Information:**

Device	Package	Shipping
MBRF3035CT	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

#### **Maximum Ratings:**

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage	$V_{RRM}$	-	35	MBRF3035CT	V
Working Peak Reverse Voltage	$V_{RWM}$		40	MBRF3040CT	
DC Blocking Voltage	$V_R$		45	MBRF3045CT	
Average Rectified Forward		50% duty cycle @T <sub>C</sub> =123 °C,		15(per leg)	Α
Current	I <sub>F</sub> (AV)	rectangular wave form	30	(per device)	
Peak One Cycle Non-Repetitive	I <sub>FSM</sub>	8.3 ms, half Sine pulse		240	Α
Surge Current (per leg)					

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#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop	$V_{F1}$	@ 15 A, Pulse, T <sub>J</sub> = 25 °C	0.70	V
(per leg)*		@ 30 A, Pulse, T <sub>J</sub> = 25 °C	0.84	
	$V_{F2}$	@ 15 A, Pulse, T <sub>J</sub> = 125 °C	0.57	V
		@ 30 A, Pulse, T <sub>J</sub> = 125 °C	0.72	
Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = rated V_R$	1.0	mA
		T <sub>C</sub> = 25 °C		
	I <sub>R2</sub>	$@V_R = rated V_R$	100	mA
		T <sub>C</sub> = 125 °C		
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$	800	pF
(per leg)		$f_{SIG} = 1MHz$		
Typical Series Inductance	Ls	Measured lead to lead 5 mm from	7.5	nΗ
(per leg)		package body		
Voltage Rate of Change	dv/dt	-	10,000	V/μs

<sup>\*</sup>Pulse Width < 300µs, Duty Cycle <2%

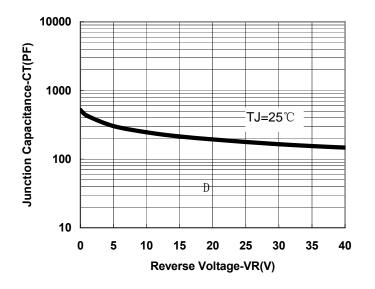
### **Thermal-Mechanical Specifications:**

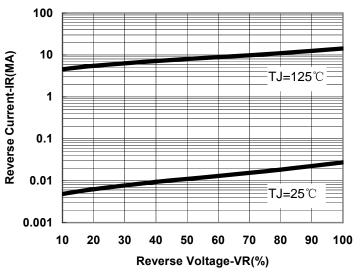
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +150	°C
Storage Temperature	$T_{stg}$	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(per leg)	$R_{\theta JC}$	DC operation	2.4	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		•

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**Fig.1-Typical Junction Capacitance** 

Fig.2-Typical Reverse Characteristics

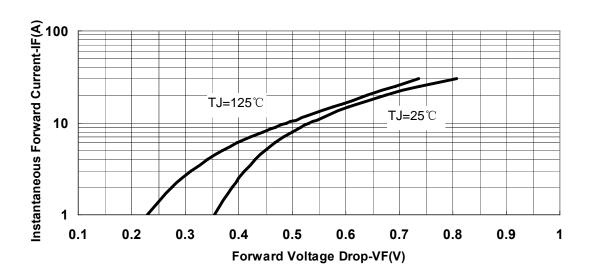


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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